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TECHNOLOGY CENTER 2800

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D. Smalls-Logan
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Applicants: S. YAMAGUCHI, et al.
Application No.: 09/698,274
Filed: October 30, 2000
For: SEMICONDUCTOR DEVICE, METHOD OF MAKING THE
SAME AND LIQUID CRYSTAL DISPLAY DEVICE
Art Group: 2826
Examiner: F. Abraham

AMENDMENT

Commissioner of Patents
Washington, D.C. 20231

January 16, 2003

Sir:

In response to the Office Action mailed October 24, 2002, please amend the above-identified application as follows:

IN THE CLAIMS:

Please cancel Claims 4, 5, 8, 9, 10, 13, 14, 15, 32, 33 and 36 without prejudice or disclaimer.

Please amend Claims 6, 7 and 12 as follows:

B¹
6. (Amended) A thin-film semiconductor device comprising an insulator, a polycrystalline layer formed on said insulator, and a transistor comprising a source region, a drain region, a gate region, and a channel region formed at the surface portion of said polycrystalline layer, said polycrystalline layer comprising crystal grains of an element selected from the group of Type-IV elements and their alloys,